

SSC8415GS6

P-Channel Enhancement Mode MOSFET

> Features

V _{DS}	V _{GS}	R _{DS(ON)} Typ.	ID
-20V	±12V	35mΩ @-4V5	-4A
		44mΩ @-2V5	-4/

> Description

This device is produced with high cell density DMOS trench technology, which is especially used to minimize on-state resistance. This device particularly suits low voltage applications such as portable equipment, power management and other battery powered circuits, and low in-line power dissipation are needed in a very small outline surface mount package.

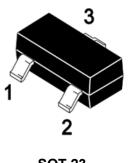
Applications

- Load Switch
- Portable Devices
- DCDC Conversion

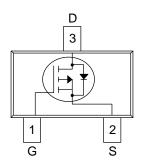
Ordering Information

Device	Package	Shipping	
SSC8415GS6	SOT-23	3000/Reel	

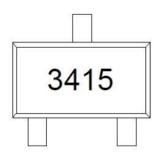
Pin configuration



SOT-23



Pin Configuration (Top View)



Marking



Absolute Maximum Ratings (T_A=25[°]C unless otherwise noted)

Symbol	Parameter	Ratings	Unit
V _{DSS}	Drain-to-Source Voltage	-20	V
V _{GSS}	Gate-to-Source Voltage	±12	V
I _D	Continuous Drain Current ^a	-4	Α
I _{DM}	Pulsed Drain Current ^b	-22	Α
P _D	Power Dissipation ^c	0.9	W
P _{DSM}	Power Dissipation ^a	0.55	W
TJ	Operation junction temperature	on temperature -55 to 150	
T _{STG}	Storage temperature range -55 to 150		$^{\circ}$

➤ Thermal Resistance Ratings (T_A=25°C unless otherwise noted)

Symbol	Parameter	Ratings	Unit
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance ^a	140	°C/W

Note:

- a. The value of R_{θJA} is measured with the device mounted on 1 in² FR-4 board with 2oz.copper, in a still air environment with T_A=25°C. The value in any given application depends on the user is specific board design. The power dissipation is based on the t≤10s thermal resistance rating.
- b. Repetitive rating, pulse width limited by junction temperature.
- c. The power dissipation P_D is based on $T_{J(MAX)}$ =150°C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heat sinking is used.

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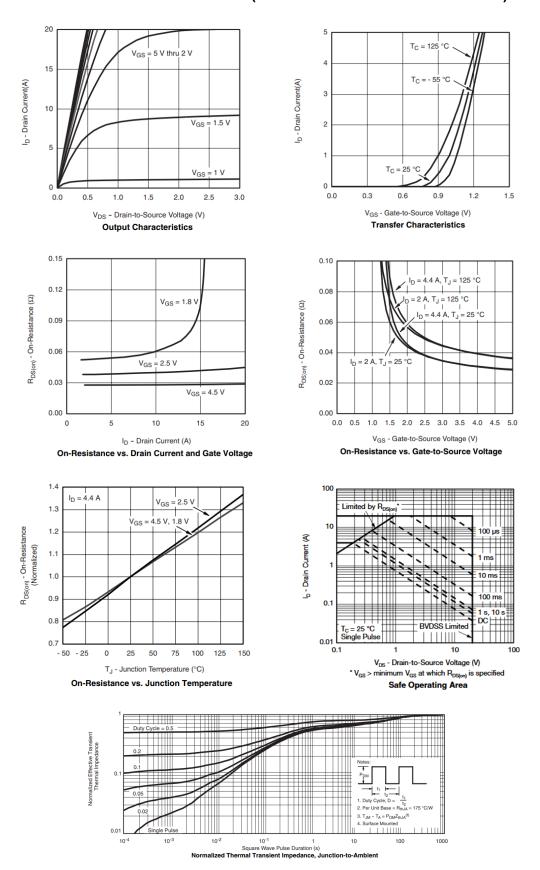


\succ Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =-10uA	-20			V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-0.4	-0.6	-0.9	V
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =-4.5V, I _D =-3.5A		35	40	mΩ
Drain-Source On-Resistance		V _{GS} =-2.5V, I _D =-3A		44	60	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-20V, V _{GS} =0V			-1	μA
Gate-Source Leak Current	Igss	V _{GS} =±12V, V _{DS} =0V			±100	nA
Forward Voltage	V_{SD}	V _{GS} =0V, I _S =-1.6A	-0.5	-0.75	-1.2	V
Input Capacitance	C _{ISS}			869		pF
Output Capacitance	Coss	$V_{DS} = -10V$, $V_{GS} = 0V$, $f = 1MHz$		265		
Reverse Transfer Capacitance	C _{RSS}			258		
Turn-on Delay Time	T _{D(ON)}			12		
Rise Time	Tr	V_{DS} =10 V , I_{D} =-1.0 A , R_{L} =6 Ω , V_{GS} =-4.5 V , R_{G} =6 Ω ,		8.9		ns
Turn-off Delay Time	T _{D(OFF)}			45		
Fall Time	T _f			15		
Total Gate Charge	Q_{G}			12		
Gate to Source Charge	Q _{GS}	V_{DS} =-10V , V_{GS} =-4.5V , I_{D} =-5A		2.1		nC
Gate to Drain Charge	Q _{GD}			2.4		

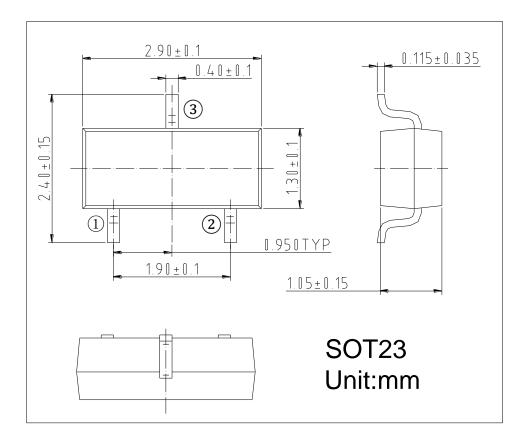


➤ Typical Performance Characteristics (T_A=25°C unless otherwise noted)

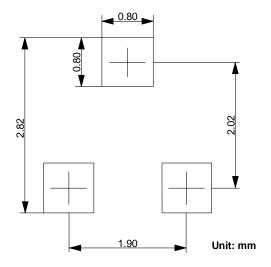




Package Information



> Recommended Pad outline





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